

# STG3685

# LOW VOLTAGE $0.5\Omega$ MAX DUAL SPDT SWITCH. SINGLE ENABLE WITH BREAK BEFORE MAKE FEATURE

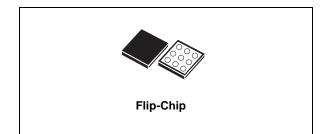
#### PRELIMINARY DATA

- HIGH SPEED:  $t_{PD} = 0.3$ ns (TYP.) at  $V_{CC} = 3.0$ V  $t_{PD} = 0.4$ ns (TYP.) at  $V_{CC} = 2.3V$
- ULTRA LOW POWER DISSIPATION:  $I_{CC} = 0.2 \mu A$  (MAX.) at  $T_A = 85^{\circ}C$
- LOW "ON" RESISTANCE  $V_1 = 0V$ :  $R_{ON} = 0.4\Omega$  (MAX.  $T_A = 25^{\circ}C$ ) at  $V_{CC} = 4.2V$  $R_{ON} = 0.5\Omega$  (MAX.  $T_A = 25^{\circ}C$ ) at  $V_{CC} = 3.0V$  $R_{ON} = 0.6\Omega$  (MAX.  $T_A = 25^{\circ}C$ ) at  $V_{CC} = 2.3V$
- WIDE OPERATING VOLTAGE RANGE: V<sub>CC</sub> (OPR) = 1.4V to 4.3V SINGLE SUPPLY
- 4.3V TOLERANT AND 1.8V COMPATIBLE THRESHOLD ON DIGITAL CONTROL INPUT at  $V_{CC}$  = 2.3 to 4.3V
- LATCH-UP PERFORMANCE EXCEEDS 300mA (JESD 17)
- ESD PERFORM. (ANALOG CHAN. vs GND): HBM > 4KV (MIL STD 883 method 3015)

#### DESCRIPTION

The STG3685 is an high-speed CMOS DUAL ANALOG S.P.D.T. (Single Pole Dual Throw) SWITCH or DUAL 2:1 Multiplexer/Demultiplexer Bus Switch fabricated in silicon gate C<sup>2</sup>MOS technology. It is designed to operate from 1.4V to 4.3V, making this device ideal for portable applications.

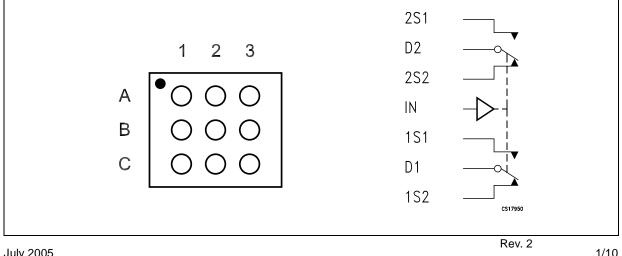
It offers very low ON-Resistance (<0.5 $\Omega$ ) at  $V_{CC}$ =3.0V. The IN input is provided to control the switches. The switches nS1 are ON (they are



#### Table 1: Order Codes

PACKAGE	T & R
Flip-Chip9	STG3685BJR

connected to common Ports Dn) when the IN input is held high and OFF (high impedance state exists between the two ports) when IN is held low; the switches nS2 are ON (they are connected to common Ports Dn) when the IN input is held low and OFF (high impedance state exists between the two ports) when IN is held high. Additional key features are fast switching speed, Break Before Make Delay Time and Ultra Low Power Consumption. All inputs and outputs are equipped with protection circuits against static discharge, giving them ESD immunity and transient excess voltage. It's available in the commercial temperature range Flip-chip package with Epoxy Protection.

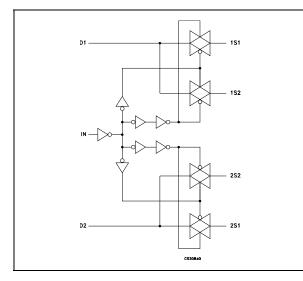


#### Figure 1: Pin Connection (Top Through View) And Schematic Circuit

July 2005

This is preliminary information on a new product now in development or undergoing evaluation. Details are subject to change without notice.

#### Figure 2: Input Equivalent Circuit



**Table 4: Absolute Maximum Ratings** 

## **Table 2: Pin Description**

PIN N°	SYMBOL	NAME AND FUNCTION
B2	IN	Control
A3, A1 C3, C1	2S1, 1S1 2S2, 1S2	Independent Chan- nels
B3, B1	D2, D1	Common Channels
C2	GND	Ground (0V)
A2	V <sub>CC</sub>	Positive Supply Voltage

#### Table 3: Truth Table

IN	SWITCH S1	SWITCH S2
Н	ON	OFF(*)
L	OFF(*)	ON

(\*) High Impedance

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply Voltage	-0.5 to 4.6	V
VI	DC Input Voltage	-0.5 to V <sub>CC</sub> + 0.5	V
V <sub>IC</sub>	DC Control Input Voltage	-0.5 to 4.6	V
Vo	DC Output Voltage	-0.5 to V <sub>CC</sub> + 0.5	V
I <sub>IKC</sub>	DC Input Diode Current on control pin (V <sub>IN</sub> < 0V)	- 50	mA
Ι <sub>ΙΚ</sub>	DC Input Diode Current (V <sub>IN</sub> < 0V)	± 50	mA
I <sub>ОК</sub>	DC Output Diode Current	± 20	mA
Ι <sub>Ο</sub>	DC Output Current	± 300	mA
I <sub>OP</sub>	DC Output Current Peak (pulse at 1ms, 10% duty cycle)	± 500	mA
$I_{CC}$ or $I_{GND}$	DC V <sub>CC</sub> or Ground Current	± 100	mA
PD	Power Dissipation at T <sub>a</sub> =70°C (1)	TBD	mW
T <sub>stg</sub>	Storage Temperature	-65 to 150	°C
ΤL	Lead Temperature (10 sec)	260	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. (1) Derate above 70°C: by 18.5mW/°C.

#### **Table 5: Recommended Operating Conditions**

Symbol	Parameter	Parameter					
V <sub>CC</sub>	Supply Voltage (note 1)	1.4 to 4.3	V				
VI	Input Voltage	0 to V <sub>CC</sub>	V				
V <sub>IC</sub>	Control Input Voltage	/oltage 0 to 4.3		V			
Vo	Output Voltage	0 to V <sub>CC</sub>	V				
T <sub>op</sub>	Operating Temperature	-55 to 125	°C				
dt/dv		V <sub>CC</sub> = 1.4V to 2.7V	0 to 20	ns/V			
ul/uv		V <sub>CC</sub> = 3.0V to 3.6V	0 to 10	115/ V			

1) Truth Table guaranteed: 1.2V to 4.3V.



# **Table 6: DC Specifications**

		Test Conditions		Value							
Symbol	Parameter	v <sub>cc</sub>		т	<sub>A</sub> = 25°	С	-40 to	85°C	-55 to	125°C	Unit
		(Ŭ)		Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
V <sub>IH</sub>	High Level	1.65-1.95		$0.65V_{CC}$			$0.65V_{CC}$		$0.65V_{CC}$		
	Input Voltage	2.3-2.5		1.4			1.4		1.4		
		2.7-3.0		1.4			1.4		1.4		v
		3.3		1.5			1.5		1.5		v
		3.6		1.6			1.6		1.6		
		4.3		1.6			1.6		1.6		
V <sub>IL</sub>	Low Level	1.65-1.95				0.40		0.40		0.40	
	Input Voltage	2.3-2.5				0.50		0.50		0.50	
		2.7-3.6				0.50		0.50		0.50	
		3.3				0.50		0.50		0.50	V
		3.6				0.50		0.50		0.50	
		4.3				0.50		0.50		0.50	
R <sub>ON</sub>	Switch ON	4.3			250	400		500			
011	Resistance (See Fig. 12)	3.0			300	500		600			
		2.7	$V_S=0V$ to $V_{CC}$		300	500		600			
		2.3	I <sub>S</sub> =100mA		350	600		800			mΩ
		1.8			550	2000		4000			
		1.4			1200	2500		5000			
R <sub>FLAT</sub>	ON	4.3									
	Resistance	3.0									
	FLATNESS	2.7	V <sub>S</sub> =0 to V <sub>CC</sub> I <sub>S</sub> =100mA		0.07	0.15		0.15			Ω
	(1)	2.3	IS=100IIIA								
		1.65									
I <sub>OFF</sub>	OFF State Leakage Current (nSn), (Dn)	4.3	V <sub>S</sub> =0.3 or 4V			±10		±100			nA
I <sub>IN</sub>	Input Leakage Current	0 - 4.3	V <sub>IN</sub> =0 to 4.3V			±0.1		± 1			μA
I <sub>CCL</sub>	Quiescent Supply Current	1.65-4.3	V <sub>IN</sub> =V <sub>CC</sub> or GND			±0.05		±0.2		±1	μA
I <sub>CCH</sub>	Quiescent	4.2	V <sub>IN</sub> =1.65V		415	500					μΑ
	Supply		V <sub>IN</sub> =1.8V	1	360	400					
	Current		V <sub>IN</sub> =2.6V		120	150					

Note 1: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

	Test (		ondition	Value							
Symbol	Parameter	V <sub>cc</sub>		T <sub>A</sub> = 25°C		-40 to 85°C		-55 to 125°C		Unit	
		(V)		Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay	1.65-1.95			0.45						
,		2.3-2.7			0.40						20
		3.0-3.6			0.30						ns
		3.6-4.3			0.30						
t <sub>ON</sub>	TURN-ON time	1.65-1.95	V <sub>S</sub> =0.8V		70						
		2.3-2.7			32	50		60			ns
		3.0-3.6	V <sub>S</sub> =1.5V		32	50		60			
		3.6-4.3	_		30	50		60			
t <sub>OFF</sub>	TURN-OFF time	1.65-1.95	V <sub>S</sub> =0.8V		45						
		2.3-2.7			25	30		40			ns
		3.0-3.6	V <sub>S</sub> =1.5V		15	30		40			115
		3.6-4.3			15	30		40			
	Break Before Make	1.65-1.95	0 25 - 5								
+_	Time Delay	2.3-2.7	C <sub>L</sub> =35pF R <sub>L</sub> = 50Ω	2	15						
t <sub>D</sub>		3.0-3.6	V <sub>S</sub> =1.5V	2	15						ns
		3.6-4.3	15-1.01	2	15						
Q	Charge injection	1.65-1.95	C <sub>L</sub> = 100pF		50						
		2.3-2.7	$R_L = 1M\Omega$		40						-C
		3.0-3.6	V <sub>GEN</sub> = 0V		35						рС
		3.6-4.3	$R_{GEN} = 0\Omega$		35						

# **Table 7: AC Electrical Characteristics** ( $C_L$ = 35pF, $R_L$ = 50 $\Omega$ , $t_r$ = $t_f \le 5ns$ )

Table 8: Analog Switch Characteristics (C<sub>L</sub> = 5pF, R<sub>L</sub> = 50 $\Omega$ , T<sub>A</sub> = 25°C)

		Те	Test Condition		Value							
Symbol	Parameter	v <sub>cc</sub>		т	A = 25°	С	-40 to	85°C	-55 to	125°C	Unit	
		(V)		Min.	Тур.	Max.	Min.	Max.	Min.	Max.		
OIRR	Off Isolation (1)	1.65-4.3	V <sub>S</sub> = 1V <sub>RMS</sub> f= 100KHz		-64						dB	
Xtalk	Crosstalk	1.65-4.3	V <sub>S</sub> = 1V <sub>RMS</sub> f= 100KHz		-32						dB	
THD	Total Harmonic Distortion	2.3-4.3	$R_{L}=600\Omega$ $V_{I}=2V_{PP}$ f = 20Hz to 20kHz		0.03						%	
BW	-3dB Bandwidth	1.65-4.3	R <sub>L</sub> = 50Ω		50						MHz	
C <sub>IN</sub>	Control Pin Input Capacitance				10							
C <sub>Sn</sub>	Sn Port Capaci- tance	3.3	f = 1MHz		35						pF	
CD	D Port Capaci- tance when Switch is Enabled	3.3	f = 1MHz		91							

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Note 1: Off Isolation = 20Log<sub>10</sub> (V<sub>D</sub>/V<sub>S</sub>), V<sub>D</sub> = output. V<sub>S</sub> = input at off switch.

## Figure 3: On Resistance

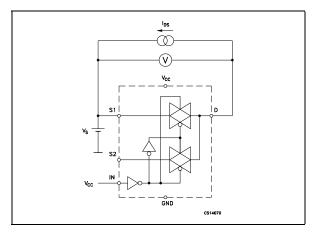


Figure 4: Off Leakage

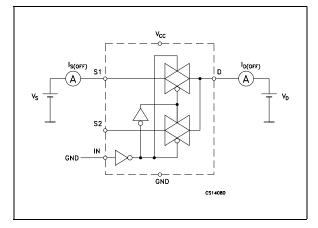
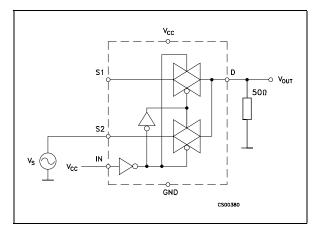
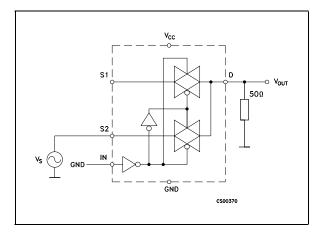


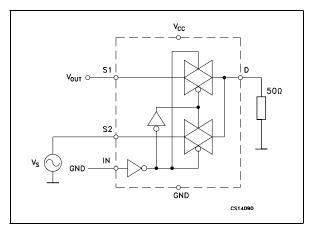
Figure 5: Off Isolation



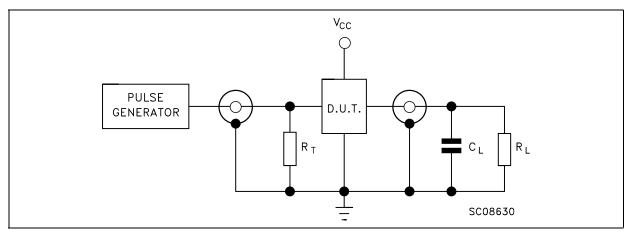
# Figure 6: Bandwidth



# Figure 7: Channel To Channel Crosstalk



#### Figure 8: Test Circuit



 $C_L = 5/35 pF$  or equivalent (includes jig and probe capacitance)

- $R_L = 50\Omega$  or equivalent
- $R_T = Z_{OUT}$  of pulse generator (typically 50 $\Omega$ )



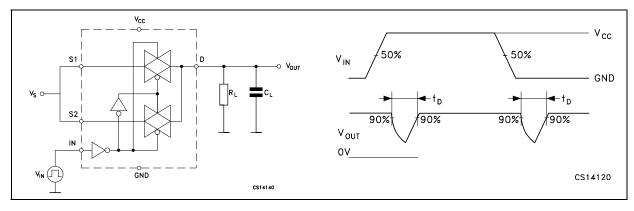
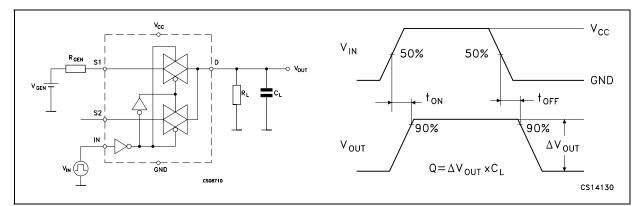
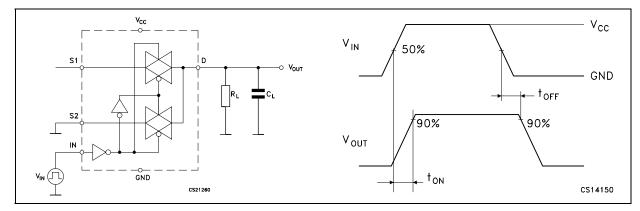


Figure 10: Charge Injection ( $V_{GEN} = 0V$ ,  $R_{GEN} = 0\Omega$ ,  $R_L = 1M\Omega$ ,  $C_L = 100$ pF)



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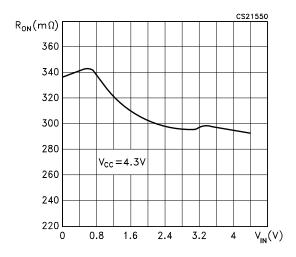
Figure 11: Turn On, Turn Off Delay Time



#### **TYPICAL CHARACTERISTICS**

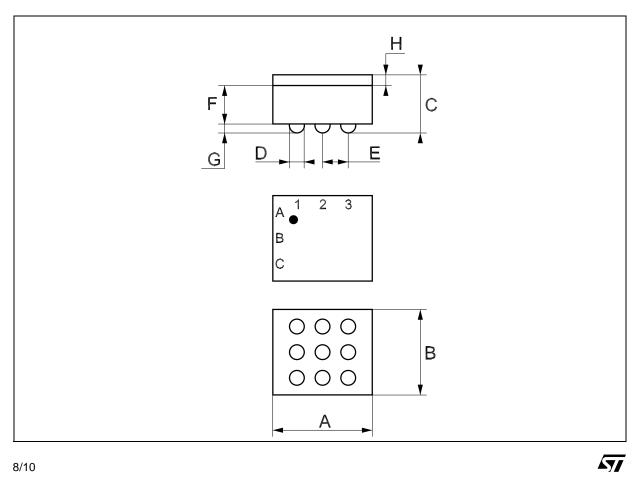
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# Figure 12: Switch-On $R_{ON}$ vs $V_{IN}$



# Flip-Chip9 MECHANICAL DATA

DIM		mm.		mils				
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.		
А	1.59	1.64	1.69	62.6	64.6	66.5		
В	1.42	1.47	1.52	55.9	57.9	59.8		
С			0.80			31.5		
D	0.295	0.32	0.345	11.6	12.6	13.6		
E		0.5			19.7			
F	0.35	0.40	0.45	13.8	15.7	17.7		
G		0.25			9.8			
Н	0.061	0.0635	0.066	2.4	2.5	2.6		



# Table 9: Revision History

Date	Revision	Description of Changes	
13-Jan-2005	1	First Release.	
04-Jul-2005	2	The Q Values on Table 7 has been updated.	

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